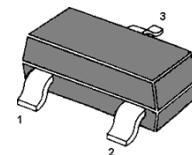


MBTSC5065 NPN Silicon Epitaxial Planar Transistor

for low noise, high gain amplifier at VHF~UHF band.

The transistor is subdivided into two groups O and Y, according to its DC current gain.



1.Base 2.Emitter 3.Collector
SOT-23 Plastic Package

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

| Parameter | Symbol | Value | Unit |
|---------------------------|-----------|-------------|------|
| Collector Base Voltage | V_{CBO} | 20 | V |
| Collector Emitter Voltage | V_{CEO} | 12 | V |
| Emitter Base Voltage | V_{EBO} | 3 | V |
| Base Current | I_B | 15 | mA |
| Collector Current | I_C | 30 | mA |
| Power Dissipation | P_{tot} | 200 | mW |
| Junction Temperature | T_j | 125 | °C |
| Storage Temperature Range | T_s | -55 to +125 | °C |

Characteristics at $T_{amb}=25\text{ }^{\circ}\text{C}$

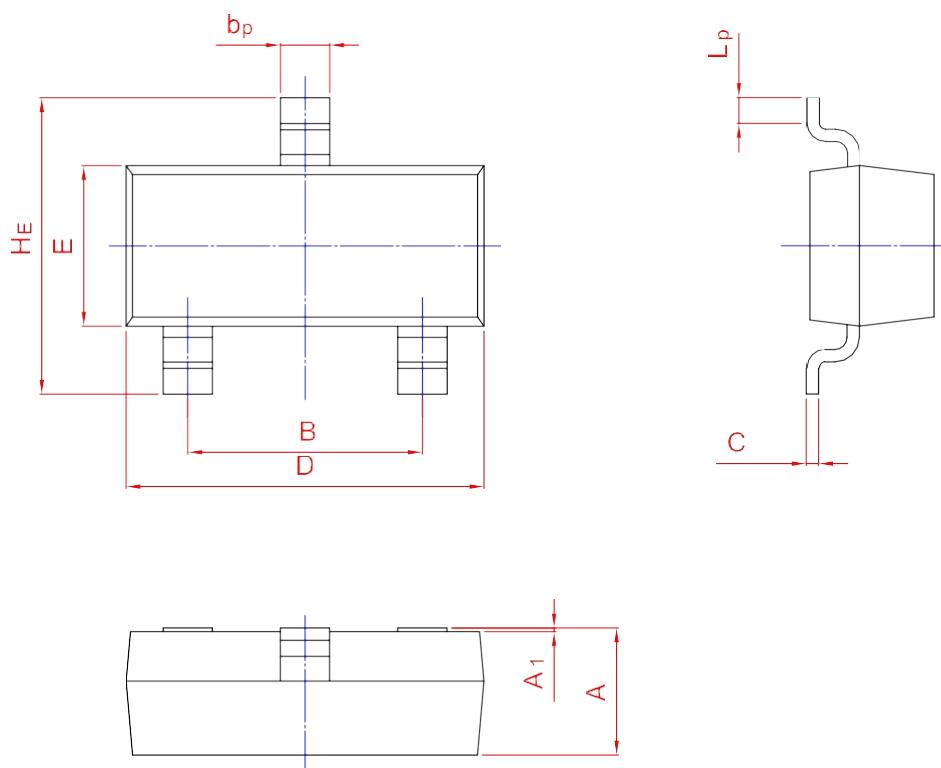
| Parameter | Symbol | Min. | Typ. | Max. | Unit |
|---|----------------------|-----------|--------|------------|---------------|
| DC Current Gain at $V_{CE}=5\text{V}$, $I_C=10\text{mA}$ | | | | | |
| Current Gain Group O Y | h_{FE} h_{FE} | 80 120 | - - | 160 240 | - - |
| Collector Cutoff Current at $V_{CB}=10\text{V}$ | I_{CBO} | - | - | 1 | μA |
| Emitter Cutoff Current at $V_{EB}=1.0\text{V}$ | I_{EBO} | - | - | 1 | μA |
| Transition Frequency at $V_{CE}=5\text{V}$, $I_C=10\text{mA}$ | f_T | 5 | 7 | - | GHz |
| Reverse Transfer Capacitance at $V_{CB}=5\text{V}$, $f=1\text{MHz}$ ¹⁾ | C_{re} | - | 0.45 | 0.9 | pF |
| Output Capacitance at $V_{CB}=5\text{V}$, $f=1\text{MHz}$ ¹⁾ | C_{ob} | - | 0.7 | - | pF |
| Insertion Gain at $V_{CE}=5\text{V}$, $I_C=10\text{mA}$, $f=500\text{MHz}$ | $ S_{21e} ^2_1$ | - | 17 | - | dB |
| Insertion Gain at $V_{CE}=5\text{V}$, $I_C=10\text{mA}$, $f=1.0\text{GHz}$ | $ S_{21e} ^2_2$ | 8.5 | 12 | - | dB |
| Noise Figure at $V_{CE}=5\text{V}$, $I_C=3\text{mA}$, $f=500\text{MHz}$ | NF_1 | - | 1 | - | dB |
| Noise Figure at $V_{CE}=5\text{V}$, $I_C=3\text{mA}$, $f=1.0\text{GHz}$ | NF_2 | - | 1.1 | 2 | dB |

¹⁾ C_{re} is measured by 3 terminal method with capacitance bridge.

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



| UNIT | A | B | b _p | C | D | E | H _E | A ₁ | L _p |
|------|--------------|--------------|----------------|--------------|--------------|--------------|----------------|----------------|----------------|
| mm | 1.40 0.95 | 2.04 1.78 | 0.50 0.35 | 0.19 0.08 | 3.10 2.70 | 1.65 1.20 | 3.00 2.20 | 0.100 0.013 | 0.50 0.20 |